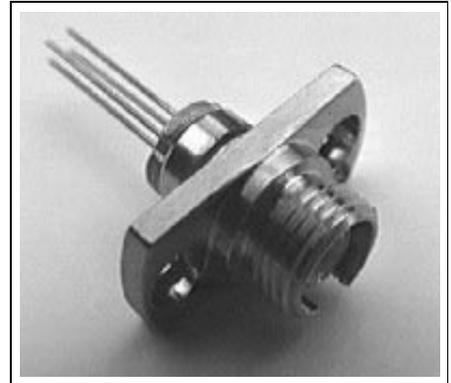


## 1550 nm Laser in Receptacle Package, Medium Power

STM 81007X

- Designed for application in fiber-optic networks
- Laser diode with Multi-Quantum Well structure
- Suitable for bit rates up to 1 Gbit/s
- Ternary photodiode at rear mirror for monitoring and control of radiant power
- Hermetically sealed subcomponents, similar to TO 18
- SM Receptacle with 2-hole flange



Type	Ordering Code	Connector/Flange
STM 81007G	Q62702-Pxxxx	FC, 2-hole

### Maximum Ratings

Output power ratings refer to the SM fiber output. The operating temperature of the submount is identical to the case temperature.

Parameter	Symbol	Values	Unit
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### Module

Operating temperature range at case	$T_C$	- 40 ... + 85	°C
Storage temperature range	$T_{stg}$	- 40 ... + 85	°C
Soldering temperature $t_{max} = 10$ s, 2 mm distance from bottom edge of case	$T_S$	260	°C

### Laser Diode

Direct forward current	$I_{F max}$	120	mA
Radiant power CW	$\Phi_e$	2	mW
Reverse voltage	$V_{R max}$	2	V

### Monitor Diode

Reverse voltage	$V_{R max}$	10	V
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**Characteristics**

All optical data refer to a coupled 10/125  $\mu\text{m}$  SM fiber,  $T_C = 25\text{ }^\circ\text{C}$ .

Parameter	Symbol	Values	Unit
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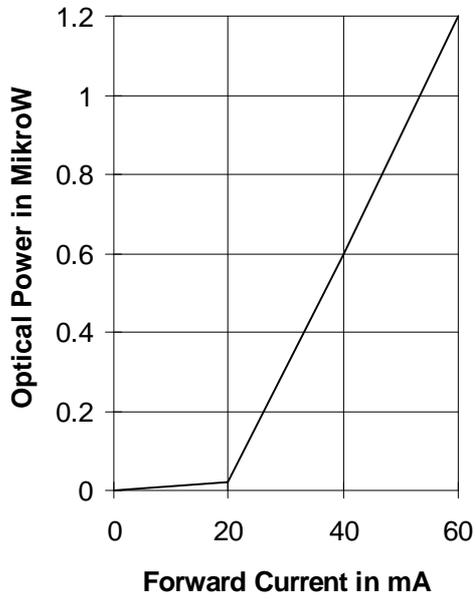
**Laser Diode**

Optical output power	$\Phi_e$	> 1.2	mW
Emission wavelength center of range $\Phi_e = 0.5\text{ mW}$	$\lambda$	1510 ... 1590	nm
Spectral bandwidth $\Phi_e = 0.5\text{ mW}$ (RMS)	$\Delta\lambda$	< 5	nm
Threshold current ( $-40\text{ }^\circ\text{C}$ ... $+85\text{ }^\circ\text{C}$ )	$I_{th}$	8 ... 60	mA
Forward voltage $\Phi_e = 0.5\text{ mW}$	$V_F$	< 1.5	V
Radiant power at threshold	$\Phi_{eth}$	< 40	$\mu\text{W}$
Slope efficiency	$\eta$	20 ... 100	mW/A
Differential series resistance	$r_S$	< 8	$\Omega$
Rise time/fall time	$t_R, t_F$	< 1	ns

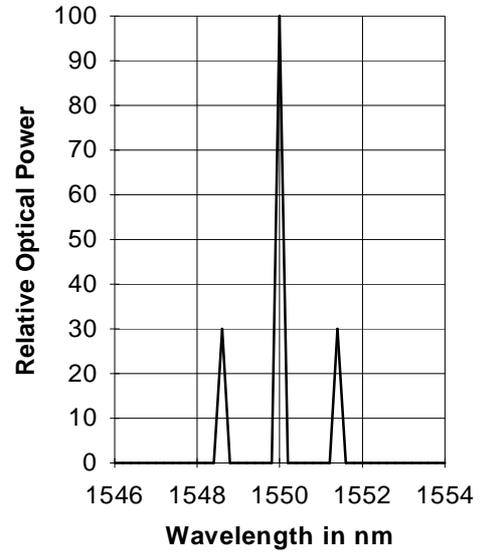
**Monitor Diode**

Dark current, $V_R = 5\text{ V}$ , $\Phi_e = 0$	$I_R$	< 500	nA
Photocurrent, $\Phi_e = 0.5\text{ mW}$	$I_P$	100 ... 1000	$\mu\text{A}$

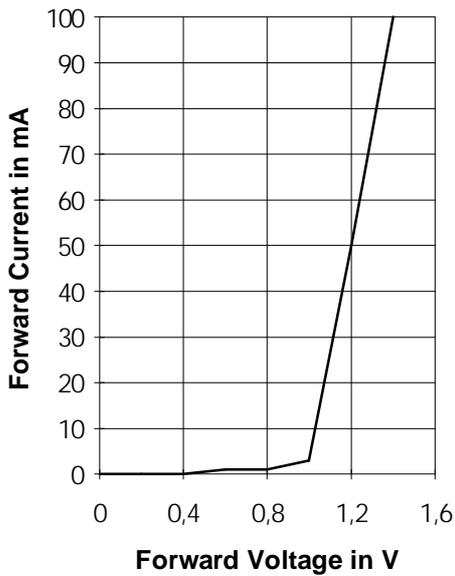
**Laser Diode**  
Radiant Power in Singlemode Fiber



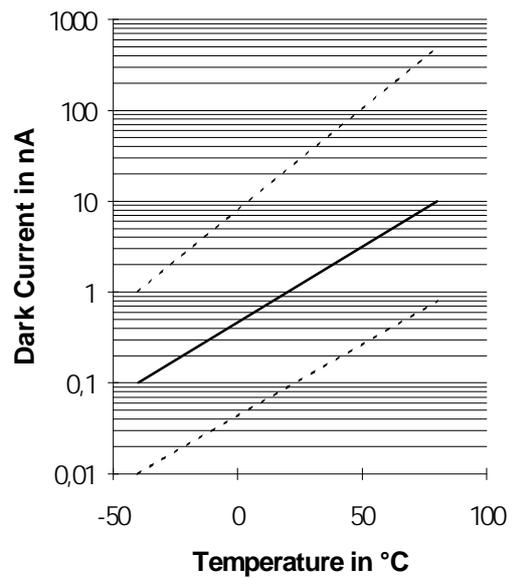
**Relative Radiant Power**  
 $\Phi_e = f(\lambda)$



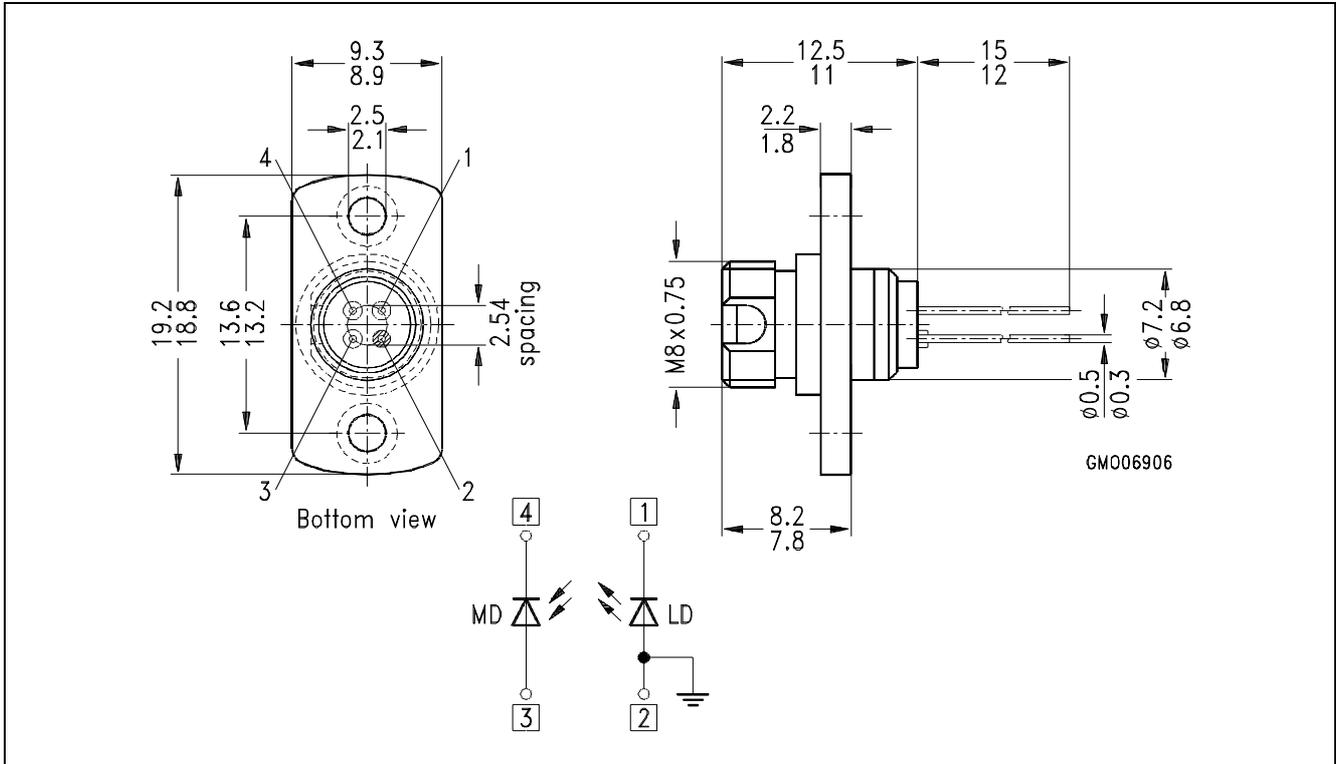
**Laser Forward Current**  
 $I_F = f(V_F)$



**Monitor Diode Dark Current  $I_R = f(T_A)$**   
 $\Phi_{port} = 0, V_R = 5 V$



Package Outlines (Dimensions in mm)



STM 81007X